## CURRENT LIMITED POWER DISTRIBUTION SWITCHES

- $80 \mathrm{~m} \Omega \mathrm{HIGH}-$ SIDE MOSFET SWITCH
- 500mA CONTINUOUS CURRENT PER CHANNEL
- INDEPENDENT THERMAL AND SHORT-CIRCUIT PROTECTION WITH OVERCURRENT LOGIC OUTPUT
- OPERATING RANGE FROM 2.7V TO 5.5V
- CMOS- AND TTL-COMPATIBLE ENABLE INPUTS
- 10 ms OC_N FAULT BLANKING
- 2.5 ms TYPICAL RISE TIME
- UNDERVOLTAGE LOCKOUT
- 20 $\quad$ A MAXIMUM STANDBY SUPPLY CURRENT
- AMBIENT TEMPERATURE RANGE, $0^{\circ} \mathrm{C}$ TO $85^{\circ} \mathrm{C}$
- ESD PROTECTION


## DESCRIPTION

The ST2054 power distribution switches is intended for application where heavy capacitive loads and short circuits are likely to be encountered. These devices incorporate $80 \mathrm{~m} \Omega$ N -channel MOSFET high-side power switches for power-distribution systems that require multiple powers switches in a single package. Each switch is controlled by an independent logic enable input. Gate drive is provided by an internal charge pump designed to control the power-switch rise times and fall times to minimize current surges during switching. The charge pump requires no external

components and allows operation from supplies as low as 2.7 V .
When the output load exceeds the current-limit threshold or a short is present, these devices limit the output current to a safe level by switching into a constant-current mode, pulling the overcurrent $(\overline{\mathrm{OCx}})$ logic output low. A 10 ms deglitching circuit provides fault-blanking feature, preventing the OC_N pin to be asserted during hot-insertion or short spikes of overcurrent conditions.
When continuous heavy overloads and short circuits increase the power dissipation in the switch, causing the junction temperature to rise, a thermal protection circuit shuts off the switch to prevent damage. Recovery from a thermal shutdown is automatic once the device has cooled sufficiently. Internal circuitry ensures the switch remains off until valid input voltage is present. These power-distribution switches are designed to current limit at 0.9 A .

Table 1: Order Codes

| Type | Temperature <br> Range | Package | Comments |
| :---: | :---: | :---: | :---: |
| ST2054BD | -40 to $85^{\circ} \mathrm{C}$ | SO-16 (Tube) | 50parts per tube $/ 40$ tube per box |
| ST2054BDR | -40 to $85^{\circ} \mathrm{C}$ | SO-16 (Tape \& Reel) | 2500 parts per reel |

Figure 1: Pin Configuration


Table 2: Pin Description

| Pln $\mathbf{N}^{\circ}$ | Symbol | Name And Function |
| :---: | :---: | :--- |
| 1 | GNDA | Ground |
| 2 | IN1 | Input Voltage |
| 3 | EN1 | Enable Input. Logic High Turns <br> On Power Switth IN-OUT1 |
| 4 | EN2 | Enable Input. Logic High Turns <br> On Power Switch IN-OUT2 |
| 5 | GNDB | Ground |
| 6 | IN2 | Input Voltage |
| 7 | EN3 | Enable Input. Logic High Turns <br> On Power Switch IN-OUT3 |
| 8 | EN4 | Enable Input. Logic High Turns <br> On Power Switch IN-OUT4 |
| 9 | $\overline{\text { OC4 }}$ | Overcurrent. Logic Output <br> Active Low IN-OUT4 |
| 10 | OUT4 | Power Switch Output <br> 11 <br> 12 <br> OUT3Power Switch Output <br> 13 <br> OC3Overcurrent. Logic Output <br> Active Low IN-OUT3 |
| 14 | OC2 | Overcurrent. Logic Output <br> Active Low IN-OUT2 |
| 15 | OUT1 | Power Switch Output <br> 16 <br> Power Switch Output <br> OC1Overcurrent. Logic Output <br> Active Low IN-OUT1 |

Table 3: Absolute Maximum Ratings

| Symbol | Parameter | Value | Unit |
| :---: | :--- | :---: | :---: |
| $\mathrm{V}_{\mathrm{I}}$ | Input Voltage Range (Note 1) | -0.3 to 6 | V |
| $\mathrm{~V}_{\mathrm{O}}$ | Output Voltage Range (Note 1) | -0.3 to $\left(\mathrm{V}_{\mathrm{I}}+0.3\right)$ | V |
| $\mathrm{V}_{\mathrm{IENX}}$ | Input Voltage Range | -0.3 to 6 | V |
| $\mathrm{I}_{\mathrm{O}}$ | Continuous Output Current | Internally Limited |  |
| ESD | Electrostatic Discharge | 2 | kV |
| $\mathrm{T}_{\mathrm{J}}$ | Operating Junction Temperature | -40 to 125 | ${ }^{\circ} \mathrm{C}$ |

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.
Note1: All voltage are referred to GND
Table 4: Recommended Operating Condition

| Symbol | Parameter | Min. | Typ. | Max. | Unit |
| :---: | :--- | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{I}}$ | Input Voltage Range (Note 1) | 2.7 |  | 5.5 | V |
| $\mathrm{~V}_{\mathrm{O}}$ | Output Voltage Range (Note 1) | 0 |  | 5.5 | V |
| $\mathrm{I}_{\mathrm{O}}$ | Continuous Output Current (Per Switch) | 0 |  | 500 | mA |

Figure 2: Block Diagram


Table 5: Power Switch Electrical Characteristics $\left(\mathrm{V}_{\mathrm{I}}=5.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=\right.$ rated current, $\mathrm{V}_{\text {IEN }}=\mathrm{V}_{\mathrm{I}}, \mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$, unless otherwise specified.) (See Note 1)

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{R}_{\mathrm{DS} \text { (ON) }}$ | Static Drain-Source ON-State Resistance | $\mathrm{V}_{1}=5 \mathrm{~V} \quad \mathrm{I}_{\mathrm{O}}=0.5 \mathrm{~A}$ |  | 80 | 100 | $\mathrm{m} \Omega$ |
|  |  | $\mathrm{V}_{\mathrm{l}}=5 \mathrm{~V} \quad \mathrm{I}_{\mathrm{O}}=0.5 \mathrm{AT}_{\mathrm{J}}=85^{\circ} \mathrm{C}$ |  | 90 | 120 |  |
|  |  | $\mathrm{V}_{1}=5 \mathrm{~V} \quad \mathrm{I}_{\mathrm{O}}=0.5 \mathrm{AT}_{\mathrm{J}}=125^{\circ} \mathrm{C}$ |  | 100 | 135 |  |
|  |  | $\mathrm{V}_{1}=3.3 \mathrm{~V} \quad \mathrm{l}_{\mathrm{O}}=0.5 \mathrm{~A}$ |  | 90 | 125 |  |
|  |  | $\mathrm{V}_{\mathrm{I}}=3.3 \mathrm{~V} \quad \mathrm{I}_{\mathrm{O}}=0.5 \mathrm{AT}_{\mathrm{J}}=85^{\circ} \mathrm{C}$ |  | 110 | 145 |  |
|  |  | $\mathrm{V}_{1}=3.3 \mathrm{~V} \mathrm{I}_{\mathrm{O}}=0.5 \mathrm{AT}_{\mathrm{J}}=125^{\circ} \mathrm{C}$ |  | 120 | 160 |  |
| $\mathrm{t}_{\mathrm{r}}$ | Output Rise Time | $\mathrm{V}_{1}=5.5 \mathrm{~V} \quad \mathrm{R}_{\mathrm{L}}=10 \Omega \mathrm{C}_{\mathrm{L}}=1 \mu \mathrm{~F}$ |  | 2.5 |  | ms |
|  |  | $\mathrm{V}_{1}=2.7 \mathrm{~V} \mathrm{R}_{\mathrm{L}}=10 \Omega \mathrm{C}_{\mathrm{L}}=1 \mu \mathrm{~F}$ |  | 3 |  |  |
| $\mathrm{t}_{\mathrm{f}}$ | Output Fall Time | $\mathrm{V}_{1}=5.5 \mathrm{~V} \mathrm{R}_{\mathrm{L}}=10 \Omega \mathrm{C}_{\mathrm{L}}=1 \mu \mathrm{~F}$ |  | 0.3 |  | ms |
|  |  | $\mathrm{V}_{\mathrm{I}}=2.7 \mathrm{~V} \quad \mathrm{R}_{\mathrm{L}}=10 \Omega \mathrm{C}_{\mathrm{L}}=1 \mu \mathrm{~F}$ |  | 0.2 |  |  |

Table 6: Enable Input ENx Characteristics $\left(\mathrm{V}_{\mathrm{I}}=5.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=\right.$ rated current, $\mathrm{V}_{\mathrm{IEN}}=\mathrm{V}_{\mathrm{I}}, \mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$, unless otherwise specified.) (See Note 1)

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
| :---: | :--- | :--- | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{IH}}$ | High level Input Voltage | $\mathrm{V}_{\mathrm{I}}=2.7 \mathrm{~V}$ to 5.5 V | 2 |  |  | V |
| $\mathrm{~V}_{\mathrm{IL}}$ | Low level Input Voltage | $\mathrm{V}_{\mathrm{I}}=4.5 \mathrm{~V}$ to 5.5 V |  |  | 0.8 | V |
|  |  | $\mathrm{~V}_{\mathrm{I}}=2.7 \mathrm{~V}$ to 4.5 V |  |  | 0.4 |  |
| $\mathrm{I}_{\mathrm{I}}$ | Input Current | $\mathrm{V}_{\mathrm{IENX}}=\mathrm{V}_{\mathrm{I}}$ or 0 V | -0.5 |  | 0.5 | $\mu \mathrm{~A}$ |
| $\mathrm{t}_{\mathrm{on}}$ | Turn-on Time | $\mathrm{R}_{\mathrm{L}}=10 \Omega \quad \mathrm{C}_{\mathrm{L}}=100 \mu \mathrm{~F}$ |  |  | 20 | ms |
| $\mathrm{t}_{\text {off }}$ | Turn-off Time | $\mathrm{R}_{\mathrm{L}}=10 \Omega \quad \mathrm{C}_{\mathrm{L}}=100 \mu \mathrm{~F}$ |  |  | 40 | ms |

Table 7: Current Limit Characteristics $\left(\mathrm{V}_{\mathrm{I}}=5.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=\right.$ rated current, $\mathrm{V}_{\mathrm{IEN}}=\mathrm{V}_{\mathrm{I}}, \mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$, unless otherwise specified.) (See Note 1)

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| IOS | Short Circuit Output Current | $V_{1}=5 \mathrm{~V}$, OUT connected to GND, device <br> enabled into short circuit | 0.7 | 1 | 1.3 | A |

Table 8: Supply Current Characteristics $\left(\mathrm{V}_{\mathrm{I}}=5.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=\right.$ rated current, $\mathrm{V}_{\mathrm{IEN}}=\mathrm{V}_{\mathrm{I}}, \mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$, unless otherwise specified.) (See Note 1)

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\text {SOL }}$ | Current Low Level Output | $\mathrm{V}_{\text {IENX }}=0$, No Load, |  | 0.05 | 2 | $\mu \mathrm{A}$ |
|  |  | $\mathrm{V}_{\text {IENX }}=0$, No Load, $\quad \mathrm{T}_{\mathrm{J}}=-40$ to $125^{\circ} \mathrm{C}$ |  |  | 20 |  |
| $\mathrm{I}_{\mathrm{SOH}}$ | Current Low High Output | $\mathrm{V}_{\text {IENX }}=\mathrm{V}_{1}$, No Load, |  | 140 | 180 | $\mu \mathrm{A}$ |
|  |  | $\mathrm{V}_{\text {IENX }}=\mathrm{V}_{\mathrm{I}}$, No Load, $\mathrm{T}_{\mathrm{J}}=-40$ to $125^{\circ} \mathrm{C}$ |  |  | 200 |  |
| $\mathrm{I}_{\mathrm{L}}$ | Output Leakage Current | $\mathrm{V}_{\text {IENX }}=0$, Output Connected to GND, $\mathrm{T}_{\mathrm{J}}=-40 \text { to } 125^{\circ} \mathrm{C}$ |  |  | 20 | $\mu \mathrm{A}$ |

Table 9: UndervoItage Characteristics $\left(\mathrm{V}_{\mathrm{I}}=5.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=\right.$ rated current, $\mathrm{V}_{\mathrm{IEN}}=\mathrm{V}_{\mathrm{I}}, \mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$, unless otherwise specified.) (See Note 1)

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
| :---: | :--- | :--- | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{IL}}$ | Low Level Input Voltage |  | 2 |  | 2.5 | V |
| $\mathrm{~V}_{\mathrm{HYS}}$ | Hysteresys |  |  | 100 |  | mV |

Table 10: Overcurrent $(\overline{\mathrm{OC}})$ Characteristics $\left(\mathrm{V}_{\mathrm{I}}=5.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=\right.$ rated current, $\mathrm{V}_{\mathrm{IEN}}=\mathrm{V}_{\mathrm{I}}, \mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$, unless otherwise specified.) (See Note 1)

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
| :---: | :--- | :--- | :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\mathrm{SINK}}$ | Sink Current | $\mathrm{V}_{\mathrm{O}}=5 \mathrm{~V}$ | 10 |  |  | mA |
| $\mathrm{~V}_{\mathrm{O}}$ | Output Low Voltage | $\mathrm{I}_{\mathrm{O}}=5 \mathrm{~mA}$ |  |  | 0.5 | V |
| $\mathrm{I}_{\mathrm{OFF}}$ | OFF-State Current | $\mathrm{V}_{\mathrm{O}}=5 \mathrm{~V} \mathrm{~V}_{\mathrm{O}}=3.3 \mathrm{~V}$ |  |  | 1 | $\mu \mathrm{~A}$ |
| $\mathrm{~T}_{\mathrm{FB}}$ | Fault-Blanking period | $\mathrm{V}_{\mathrm{I}}=5.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C}($ See Note 2 and 3$)$ | 2 | 10 |  | ms |

Note 1: Pulse testing techniques maintain junction temperature close to ambient temperature: thermal effect must be takes into account separately.
Note 2: Specified by design, not production tested.
Note 3: Guaranteed by design.
Figure 3: Test Circuit


Figure 4: Waveform - Propagation Delays ( $\mathrm{f}=1 \mathrm{MHz} ; 50 \%$ duty cycle)


## SO-16 MECHANICAL DATA

| DIM. | mm. |  |  | inch |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | TYP | MAX. | MIN. | TYP. | MAX. |
| A |  |  | 1.75 |  |  | 0.068 |
| a1 | 0.1 |  | 0.25 | 0.004 |  | 0.010 |
| a2 |  |  | 1.64 |  |  | 0.063 |
| b | 0.35 |  | 0.46 | 0.013 |  | 0.018 |
| b1 | 0.19 |  | 0.25 | 0.007 |  | 0.010 |
| C |  | 0.5 |  |  | 0.019 |  |
| c1 | $45^{\circ}$ (typ.) |  |  |  |  |  |
| D | 9.8 |  | 10 | 0.385 |  | 0.393 |
| E | 5.8 |  | 6.2 | 0.228 |  | 0.244 |
| e |  | 1.27 |  |  | 0.050 |  |
| e3 |  | 8.89 |  |  | 0.350 |  |
| F | 3.8 |  | 4.0 | 0.149 |  | 0.157 |
| G | 4.6 |  | 5.3 | 0.181 |  | 0.208 |
| L | 0.5 |  | 1.27 | 0.019 |  | 0.050 |
| M |  |  | 0.62 |  |  | 0.024 |
| S | $8^{\circ}$ (max.) |  |  |  |  |  |



## Tape \& Reel SO-16 MECHANICAL DATA

| DIM. | mm. |  |  | inch |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | TYP | MAX. | MIN. | TYP. | MAX. |
| A |  |  | 330 |  |  | 12.992 |
| C | 12.8 |  | 13.2 | 0.504 |  | 0.519 |
| D | 20.2 |  |  | 0.795 |  |  |
| N | 60 |  | 22.4 |  |  | 0.882 |
| T |  |  | 10.5 | 0.406 |  | 0.262 |
| Ao | 6.45 |  | 2.3 | 0.082 |  | 0.090 |
| Ko | 2.1 |  | 4.1 | 0.153 |  | 0.161 |
| Po | 3.9 |  |  | 8.1 | 0.311 |  |
| P | 7.9 |  |  |  |  | 0.319 |



Note: Drawing not in scale

Table 11: Revision History

| Date | Revision | Description of Changes |
| :---: | :---: | :--- |
| 28-Oct-2004 | 2 | Maturity Change. |
| 13-Jul-2005 | 3 | Add bullet on pag. 1, add paragraph in the description on pag. 1 and add <br> row $\mathrm{T}_{\text {FB }}$ on Table 10. |

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